

Matric No.:

Section:

Name:



الجامعة الإسلامية العالمية ماليزيا
INTERNATIONAL ISLAMIC UNIVERSITY MALAYSIA
يُؤْتِي سُنَّتِي إِسْلَامًا وَأَنْتَارَ إِحْسَانًا مَلِكِيًّا

KULLIYAH OF ENGINEERING

**MIDTERM EXAMINATION
SEMESTER I, 2023/2024 SESSION**

Programme : **BEEE**

Level of Study : **UG 2**

Time : **8:00 pm - 10:00 pm**

Date : **22/11/2023**

Duration : **2 Hrs.**

Course Code : **EECE 2313**

Section(s) : **1-3**

Course Title : **Electronic Circuits**

This Question Paper Consists of 6 (Six) Printing Pages (Including Cover Page) with 3 (Three) Questions.

INSTRUCTION(S) TO CANDIDATES

- Total mark of this examination is 25.
- This examination is worth 25% of the total course assessment.
- Answer **ALL QUESTIONS**.
- Marks assigned to each problem are listed in the margins.
- Write your answer on the question paper only, no additional page will provided.
- Write your answer using a pen, however, you can use a pencil for drawing the figure.

Q1	Q2	Q3	Total
8	6	11	25

Question 1 [8 marks]

(a) Derive the voltage transfer function step by step for the RC-circuit shown in Fig. 1 (a) as standard format. (3 marks)

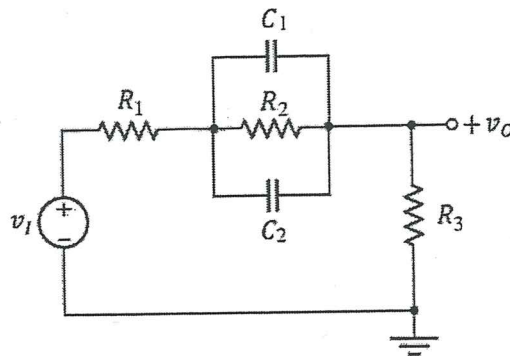
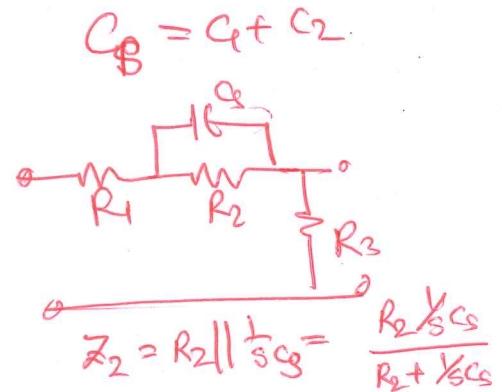


Fig. 1(a)



$$Z_s = R_1 + \frac{R_2}{1 + sC_s R_2}$$

$$Z_s + Z_p = R_1 + \frac{R_2}{1 + sC_s R_2} + R_3 = \frac{(R_1 + R_2 + R_3) + (R_1 + R_2)sC_s R_2}{1 + sC_s R_2} = \frac{R_2}{1 + sC_s R_2}$$

$$T(s) = \frac{Z_p}{Z_s + Z_p} = \frac{R_3 (1 + sC_s R_2)}{R_1 + R_2 + R_3 + s(R_1 + R_2)R_3 C_s}$$

$$= \frac{R_3}{R_1 + R_2 + R_3} \cdot \frac{1 + sC_s R_2}{1 + s \frac{(R_1 + R_2)R_3 C_s}{R_1 + R_2 + R_3}}$$

$$= K \cdot \frac{1 + s\tau_1}{1 + s\tau_2}$$

$$\tau_1 = C_s R_2 \quad \leftarrow$$

$$\tau_2 = C_s (R_1 + R_2) \parallel R_3 \quad \leftarrow$$

(b) Assume that the circuit components of Fig. 1(a) are $R_1 = 1.0 \text{ k}\Omega$, $R_2 = 5.0 \text{ k}\Omega$, $R_3 = 2.5 \text{ k}\Omega$, $C_1 = 5.0 \text{ pF}$, and $C_2 = 15.0 \text{ pF}$ respectively. (3 marks)

- i. Determine the -3dB corner frequency for the circuit
- ii. Determine the magnitude of the transfer function at -3dB corner frequency
- iii. Determine the phase of the transfer function at -3dB corner frequency

(i)

$$f_1 = \frac{1}{2\pi\tau_1} = \frac{1}{2\pi \times 20\text{p} \times 5\text{k}} = 1.59 \text{ MHz}$$

$$f_2 = \frac{1}{2\pi\tau_2} = \frac{1}{2\pi \times 20\text{p} \times 1.7647\text{k}} = 4.509 \text{ MHz}$$

$$\tau_1 = (C_1 + C_2)R_2 = (5+15)\text{p} \times 5\text{k} = 20\text{p} \times 5\text{k} = (C_1 + C_2) \left[\frac{R_1 R_2}{R_1 + R_2} \right] = 20\text{p} \times 1.7647\text{k}$$

$$\frac{\tau_1}{\tau_2} = \frac{5\text{k}}{1.7647\text{k}} = 2.83$$

$$K = \frac{R_3}{R_1 R_2 + R_3} = \frac{2.5}{85} = 0.29$$

(ii)

$$T|_{f_1} = 0.29 \times \frac{1+j1}{1+j2.83}$$

$$T|_{f_2} = 0.29 \times \frac{1+j1}{1+j2.83}$$

(c) The transfer function of an RC-circuit is represented as, (2 marks)

$$T(j\omega) = 5.0 + j10.72$$

Represent the transfer function in,

- i. Exponential form
- ii. Polar form

$$\text{Polar} = \sqrt{5^2 + 10.72^2} \angle \tan^{-1} \frac{10.72}{5}$$

$$= 11.828 \angle 64.99^\circ$$

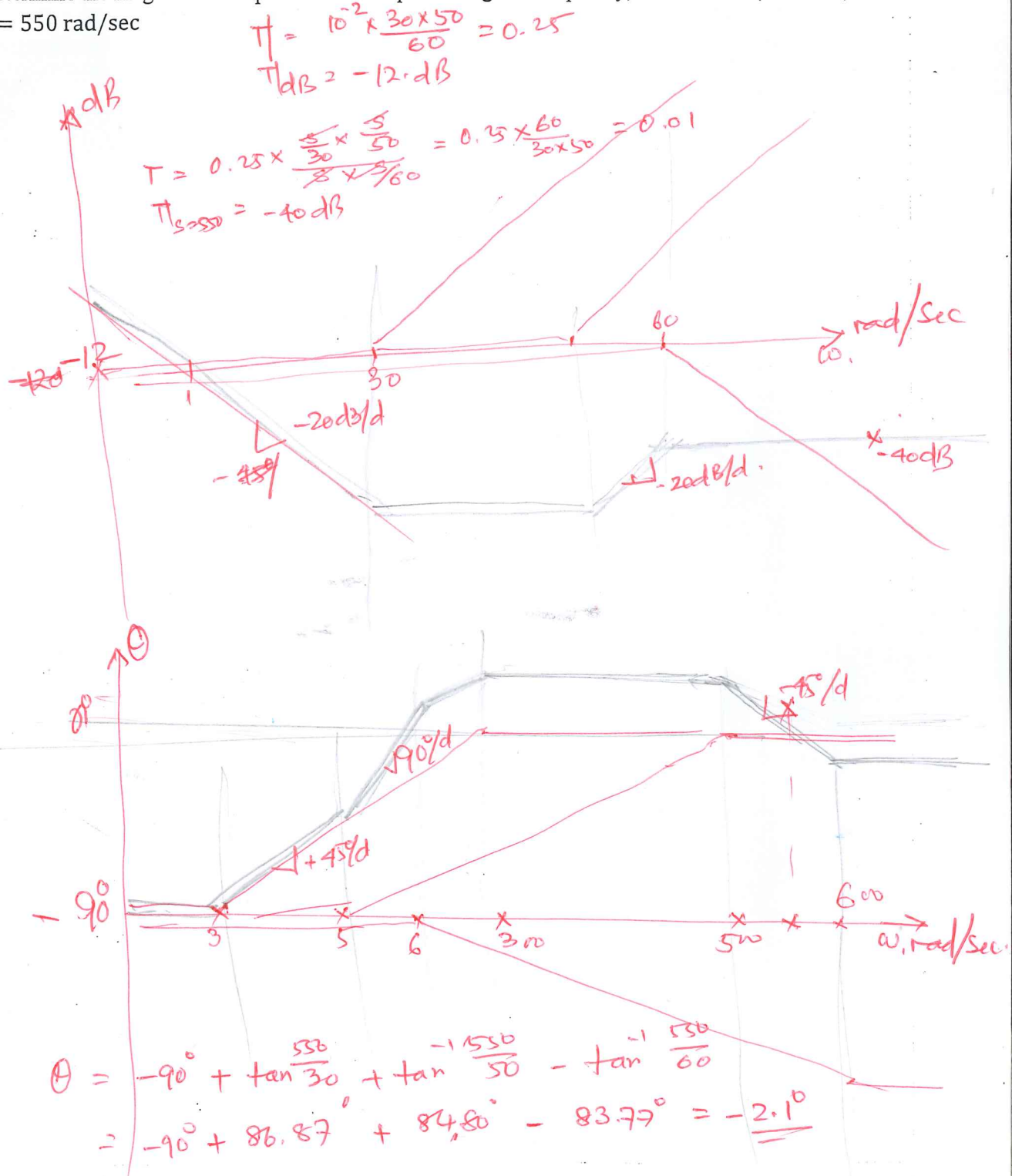
$$\text{Exponential } T = 11.828 e^{j64.99^\circ}$$

Question 2 [6 marks]

- (a) Plot the Bode magnitude and phase for the following transfer function. (4 marks)

$$T(s) = \frac{10^{-2}(s + 30)(s + 50)}{s(s + 60)}$$

- (b) Determine the magnitude and phase from the plot at angular frequency, $s = 550$ rad/sec (2 marks)



Question 3 [11 marks]

A common source audio amplifier is shown in Fig. 3 with the following circuit component values, $R_{Si} = 7.5 \text{ k}\Omega$, $R_G = 15 \text{ k}\Omega$, $R_S = 1.0 \text{ k}\Omega$, $R_D = 5 \text{ k}\Omega$, $R_L = 5 \text{ k}\Omega$ and $C_{C1} = \infty$. The MOSFET has AC small-signal parameters, $g_m = 5.0 \text{ mA/V}$, and $r_o = \infty$.

(a) Design the amplifier circuit for the lower corner frequency 20 Hz. (marks 2)

(b) Draw the small-signal equivalent circuit and determine the maximum voltage gain of the designed amplifier in dB. (marks 3)

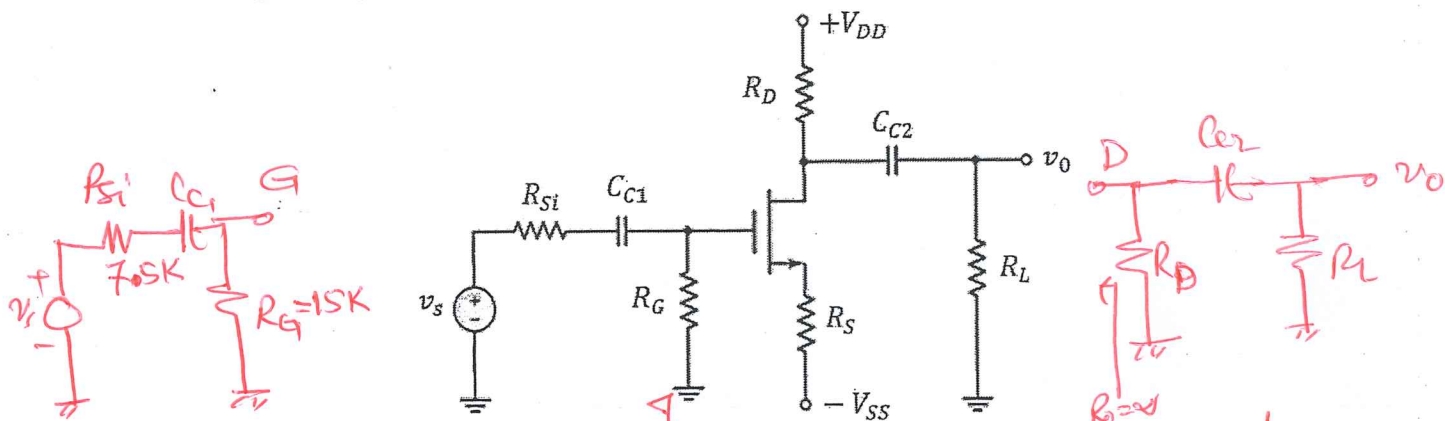


Fig. 3

$$C_{C1} = \frac{1}{2\pi f (R_{Si} + R_G)}$$

$$= \frac{1}{2\pi \times 20 [7.5 + 15] \text{ k}}$$

$$= 0.3536 \mu\text{F}$$

$$C_{C2} = \frac{1}{2\pi f (R_D + R_L)}$$

$$= \frac{1}{2\pi \times 20 [5 + 5] \text{ k}}$$

$$= 0.795 \mu\text{F}$$

$$R_i' = R_G = 15 \text{ k}$$

$$A_{VA} = \frac{-g_m v_{gs} R_i'}{v_{gs} + g_m v_{gs} R_S}$$

$$= \frac{-g_m R_i'}{1 + g_m R_S} = \frac{5 \text{ m} \times 2.5 \text{ k}}{1 + 5 \text{ m} \times 1 \text{ k}} = -\frac{12.5}{1.5} = -2.08$$

$$A_V = A_{VA} \times \frac{R_i'}{R_{Si} + R_G} = -2.08 \times \frac{15}{(7.5 + 15)} = -1.388$$

$$A_V / \text{dB} = 20 \log_{10} (1.388) = 2.853 \text{ dB} \leftarrow$$

(c) A short-circuit common-emitter amplifier small-signal equivalent circuit using a simplified BJT high-frequency model is shown in Fig. 3(c).

- i. Derive the high frequency short-circuit current gain expression stepwise and determine the f_β frequency. (4 marks)
- ii. If the BJT small-signal parameters values are, $\beta_0 = 100, r_\pi = 750\Omega, r_o = 100\text{ k}\Omega, C_\pi = 10\text{ pF}$ and $C_\mu = 2\text{ pF}$ determine the cut-off frequency of the transistor. (2 marks)

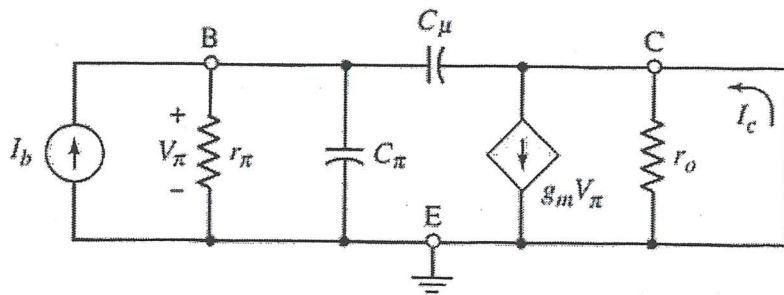


Fig. 3(c)

①

$$f_b = \frac{V_\pi}{r_\pi} + \frac{V_\pi}{sC_\pi} + \frac{V_\pi}{sC_\mu} = \frac{V_\pi}{r_\pi} \left[1 + s r_\pi (C_\pi + C_\mu) \right]$$

$$I_c = g_m V_\pi - V_\pi s C_\mu = V_\pi \left[g_m - s C_\mu \right]$$

$$\therefore A_T = \frac{I_c}{I_b} = \frac{V_\pi (g_m - s C_\mu)}{\frac{V_\pi}{r_\pi} \left[1 + s r_\pi (C_\pi + C_\mu) \right]} = \frac{g_m r_\pi - s C_\mu r_\pi}{1 + s r_\pi (C_\pi + C_\mu)}$$

$\because g_m r_\pi \gg s C_\mu r_\pi$

$$= \frac{g_m r_\pi}{1 + s r_\pi (C_\pi + C_\mu)} = \frac{\beta}{1 + s r_\pi (C_\pi + C_\mu)} \quad \therefore f_\beta = \frac{1}{2\pi r_\pi (C_\pi + C_\mu)}$$

ii)

$$f_\beta = \frac{1}{2\pi r_\pi (C_\pi + C_\mu)} = \frac{1}{2\pi \cdot 750 (10 + 2)\text{ pF}} = 17.6838\text{ MHz}$$

$$\therefore f_T = \beta f_\beta = 100 \times 17.6838 = \underline{\underline{1.768\text{ GHz}}}$$